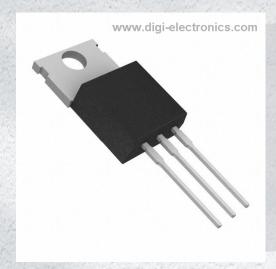


TIP29BG Datasheet



https://www.DiGi-Electronics.com

DiGi Electronics Part Number

TIP29BG-DG

Manufacturer

onsemi

Manufacturer Product Number

TIP29BG

Description

TRANS NPN 80V 1A TO220

Detailed Description

Bipolar (BJT) Transistor NPN 80 V 1 A 3MHz 2 W Thro

ugh Hole TO-220



Tel: +00 852-30501935

RFQ Email: Info@DiGi-Electronics.com

DiGi is a global authorized distributor of electronic components.



Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
TIP29BG	onsemi
Series:	Product Status:
	Active
Transistor Type:	Current - Collector (Ic) (Max):
NPN	1 A
Voltage - Collector Emitter Breakdown (Max):	Vce Saturation (Max) @ lb, lc:
80 V	700mV @ 125mA, 1A
Current - Collector Cutoff (Max):	DC Current Gain (hFE) (Min) @ Ic, Vce:
300μΑ	15 @ 1A, 4V
Power - Max:	Frequency - Transition:
2 W	3MHz
Operating Temperature:	Mounting Type:
-65°C ~ 150°C (TJ)	Through Hole
Package / Case:	Supplier Device Package:
TO-220-3	TO-220
Base Product Number:	
TIP29	

Environmental & Export classification

8541.29.0095

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	Not Applicable
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	



Complementary Silicon Plastic Power Transistors

TIP29, A, B, C (NPN), TIP30, A, B, C (PNP)

Designed for use in general purpose amplifier and switching applications. Compact TO-220 package.

Features

• These Devices are Pb-Free and are RoHS Compliant*

MAXIMUM RATINGS

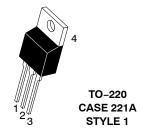
Symbol	Rating	Value	Unit
V _{CEO}	Collector - Emitter Voltage TIP29G, TIP30G TIP29AG, TIP30AG TIP29BG, TIP30BG TIP29CG, TIP30CG	40 60 80 100	Vdc
V _{CB}	Collector – Base Voltage TIP29G, TIP30G TIP29AG, TIP30AG TIP29BG, TIP30BG TIP29CG, TIP30CG	40 60 80 100	Vdc
V _{EB}	Emitter – Base Voltage	5.0	Vdc
I _C	Collector Current – Continuous	1.0	Adc
I _{CM}	Collector Current - Peak	3.0	Adc
I _B	Base Current	0.4	Adc
P _D	Total Power Dissipation @ T _C = 25°C Derate above 25°C	30 0.24	W W/°C
P _D	Total Power Dissipation @ T _A = 25°C Derate above 25°C	2.0 0.016	W W/°C
E	Unclamped Inductive Load Energy (Note 1)	32	mJ
T _J , T _{stg}	Operating and Storage Junction Temperature Range	-65 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

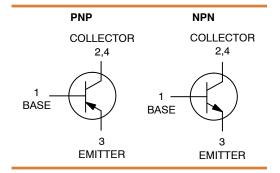
1. This rating based on testing with L_C = 20 mH, R_{BE} = 100 Ω , V_{CC} = 10 V, I_C = 1.8 Å, P.R.F = 10 Hz

THERMAL CHARACTERISTICS

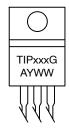
Symbol	Characteristic	Max	Unit
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient	62.5	°C/W
$R_{\theta JC}$	Thermal Resistance, Junction-to-Case	4.167	°C/W



1 AMPERE POWER TRANSISTORS **COMPLEMENTARY SILICON** 40, 60, 80, 100 VOLTS, **80 WATTS**



MARKING DIAGRAM



TIPxxx = Device Code:

29, 29A, 29B, 29C

30, 30A, 30B, 30C

= Assembly Location

= Work Week

WW = Pb-Free Package

ORDERING INFORMATION

See detailed ordering and shipping information on page 4 of this data sheet.

1

^{*}For additional information on our Pb-Free strategy and soldering details, please download the onsemi Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

TIP29, A, B, C (NPN), TIP30, A, B, C (PNP)

ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted)

Symbol	Characteristic	Min	Max	Unit
OFF CHARA	CTERISTICS			1
V _{CEO(sus)}	Collector-Emitter Sustaining Voltage (I _C = 30 mAdc, I _B = 0) (Note 2) TIP29G, TIP30G TIP29AG, TIP30AG TIP29BG, TIP30BG TIP29CG, TIP30CG	40 60 80 100	- - - -	Vdc
I _{CEO}	Collector Cutoff Current $ \begin{array}{l} (V_{CE}=30~Vdc,~I_B=0) \\ TIP29G,~TIP29AG,~TIP30G,~TIP30AG \\ (V_{CE}=60~Vdc,~I_B=0) \\ TIP29BG,~TIP29CG,~TIP30BG,~TIP30CG \\ \end{array} $	-	0.3 0.3	mAdc
I _{CES}	Collector Cutoff Current $ (V_{CE}=40 \text{ Vdc}, V_{EB}=0) $ $ \text{TiP29G}, \text{TiP30G} $ $ (V_{CE}=60 \text{ Vdc}, V_{EB}=0) $ $ \text{TiP29AG}, \text{TiP30AG} $ $ (V_{CE}=80 \text{ Vdc}, V_{EB}=0) $ $ \text{TiP29BG}, \text{TiP30BG} $ $ (V_{CE}=100 \text{ Vdc}, V_{EB}=0) $ $ \text{TiP29CG}, \text{TiP30CG} $	- - -	200 200 200 200	μAdc
I _{EBO}	Emitter Cutoff Current (V _{BE} = 5.0 Vdc, I _C = 0)	-	1.0	mAdc
ON CHARAC	TERISTICS (Note 2)			
h _{FE}	DC Current Gain ($I_C = 0.2$ Adc, $V_{CE} = 4.0$ Vdc) ($I_C = 1.0$ Adc, $V_{CE} = 4.0$ Vdc)	40 15	- 75	-
V _{CE(sat)}	Collector-Emitter Saturation Voltage (I _C = 1.0 Adc, I _B = 125 mAdc)	-	0.7	Vdc
V _{BE(on)}	Base-Emitter On Voltage (I _C = 1.0 Adc, V _{CE} = 4.0 Vdc)	-	1.3	Vdc
DYNAMIC CI	HARACTERISTICS			•
f _T	Current-Gain - Bandwidth Product (Note 3) (I _C = 200 mAdc, V _{CE} = 10 Vdc, f _{test} = 1.0 MHz)	3.0	-	MHz
h _{fe}	Small-Signal Current Gain (I _C = 0.2 Adc, V _{CE} = 10 Vdc, f = 1.0 kHz)	20	-	-
	•		•	•

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

2. Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 2.0%

3. $f_T = |h_{fe}| \bullet f_{test}$

TIP29, A, B, C (NPN), TIP30, A, B, C (PNP)

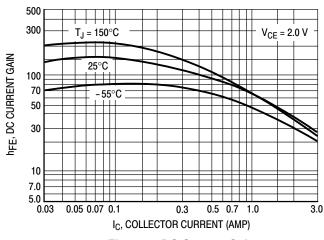


Figure 1. DC Current Gain

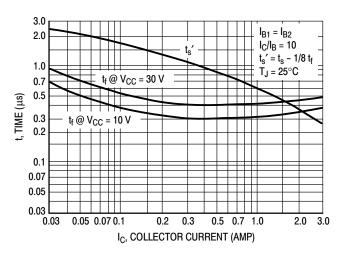


Figure 2. Turn-Off Time

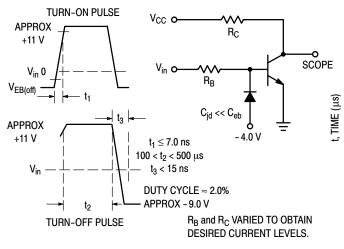


Figure 3. Switching Time Equivalent Circuit

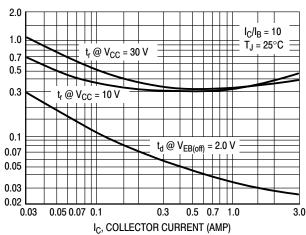


Figure 4. Turn-On Time

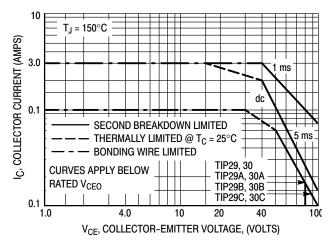


Figure 5. Active Region Safe Operating Area

There are two limitations on the power handling ability of a transistor: average junction temperature and second breakdown. Safe operating area curves indicate I_C – V_{CE} operation; i.e., the transistor must not be subjected to greater dissipation than the curves indicate.

The data of Figure 5 is based on $T_{J(pk)} = 150^{\circ}C$; T_{C} is variable depending on conditions. Second breakdown pulse limits are valid for duty cycles to 10% provided $T_{J(pk)} \le 150^{\circ}C$. At high case temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by second breakdown.

TIP29, A, B, C (NPN), TIP30, A, B, C (PNP)

ORDERING INFORMATION

Device	Package	Shipping
TIP29G	TO-220 (Pb-Free)	50 Units / Rail
TIP29AG	TO-220 (Pb-Free)	50 Units / Rail
TIP29BG	TO-220 (Pb-Free)	50 Units / Rail
TIP29CG	TO-220 (Pb-Free)	50 Units / Rail
TIP30G	TO-220 (Pb-Free)	50 Units / Rail
TIP30AG	TO-220 (Pb-Free)	50 Units / Rail
TIP30BG	TO-220 (Pb-Free)	50 Units / Rail
TIP30CG	TO-220 (Pb-Free)	50 Units / Rail



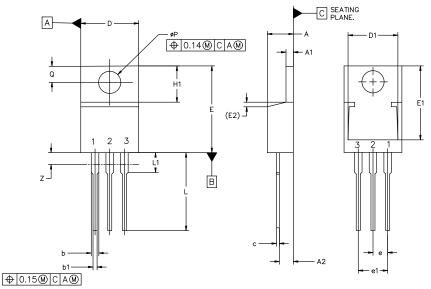
MECHANICAL CASE OUTLINE

PACKAGE DIMENSIONS



TO-220-3 10.10x15.12x4.45, 2.54P CASE 221A **ISSUE AL**

DATE 05 FEB 2025



MILLIMETERS						
DIM	MIN NOM MAX					
Α	4.07	4.45	4.83			
A1	1.15	1.28	1.41			
A2	2.04	2.42	2.79			
b	1.15	1.34	1.52			
b1	0.64	0.80	0.96			
С	0.36	0.49	0.61			
D	9.66	10.10	10.53			
D1	8.43	8.63	8.83			
Е	14.48	15.12	15.75			
E1	12.58	12.78	12.98			
E2	1.27 REF					

MILLIMETERS					
DIM	MIN	NOM	MAX		
е	2.42	2.54	2.66		
e1	4.83	5.08	5.33		
H1	5.97	6.22	6.47		
L	12.70	13.49	14.27		
L1	2.80	3.45	4.10		
Q	2.54	2.79	3.04		
ØΡ	3.60	3.85	4.09		
Z			3.48		

NOTES:

- NOTES:

 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2018.

 2. CONTROLLING DIMENSION: MILLIMETERS.

 3. DIMENSION Z DEFINES A ZONE WHERE ALL BODY AND LEAD IRREGULARITIES ARE ALLOWED.

STYLE 1:		STYLE 2:		STYLE 3:		STYLE 4:	
PIN 1.	BASE	PIN 1.	BASE	PIN 1.	CATHODE	PIN 1.	MAIN TERMINAL 1
2.	COLLECTOR	2.	EMITTER	2.	ANODE	2.	MAIN TERMINAL 2
3.	EMITTER	3.	COLLECTOR	3.	GATE	3.	GATE
4.	COLLECTOR	4.	EMITTER	4.	ANODE	4.	MAIN TERMINAL 2
STYLE 5:		STYLE 6:		STYLE 7:		STYLE 8:	
PIN 1.	GATE	PIN 1.	ANODE	PIN 1.	CATHODE	PIN 1.	CATHODE
2.	DRAIN	2.	CATHODE	2.	ANODE	2.	ANODE
3.	SOURCE	3.	ANODE	3.	CATHODE	3.	EXTERNAL TRIP/DELAY
4.	DRAIN	4.	CATHODE	4.	ANODE	4.	ANODE
STYLE 9:		STYLE 10:		STYLE 11:		STYLE 12:	
PIN 1.	GATE	PIN 1.	GATE	PIN 1.	DRAIN	PIN 1.	MAIN TERMINAL 1
2.	COLLECTOR	2.	SOURCE	2.	SOURCE	2.	MAIN TERMINAL 2
3.	EMITTER	3.	DRAIN	3.	GATE	3.	GATE
4.	COLLECTOR	4.	SOURCE	4.	SOURCE	4.	NOT CONNECTED

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